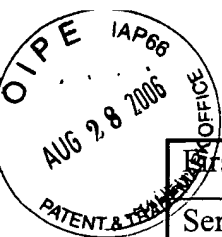


First Named Inventor	Zhongze Wang	<b>GENERAL TRANSMITTAL FORM UNDER 37 CFR 1.8 (LARGE ENTITY)</b>
Serial No.	10/758,059	
Filing Date	January 15, 2004	
Group Art Unit	2823	
Examiner Name	Thanh V. Pham	
Confirmation No.	5110	
Attorney Docket No.	400.147US02	
Title: FET HAVING EPITAXIAL SILICON GROWTH		

Mail Stop: ISSUE FEE  
Commissioner for Patents  
P. O. Box 1450  
Alexandria, VA 22313-1450

<b>Enclosures</b>			
<b>The following documents are enclosed:</b>			
<input checked="" type="checkbox"/>	Form PTOL-85 (Issue Fee Transmittal) in duplicate (1 pg.);		
<input checked="" type="checkbox"/>	"Fee Address" Indication Form (1 pg.);		
<input checked="" type="checkbox"/>	Communication re: Comments on Examiner's Statement of Reasons for Allowance (1 pg.);		
<input checked="" type="checkbox"/>	A check in the amount of \$1,400.00 (Issue Fee);		
<input checked="" type="checkbox"/>	A check in the amount of \$300.00 (Publication Fee);		
<input checked="" type="checkbox"/>	A check in the amount of \$12.00 (advance order of 4 patent copies);		
<input checked="" type="checkbox"/>	An itemized return-receipt postcard		
Leffert Jay & Polglaze, P.A. P.O. Box 581009 Minneapolis, MN 55458-1009 T – 612/312-2200 F – 612/312-2250			
<b>Please charge any additional fees or credit any overpayments to Deposit Account No. 501373.</b>			
<b>CUSTOMER NO. 27073</b>			
<b>Submitted By</b>			
Name	Tod A. Myrum	Reg. No.	42,922
Telephone	(612) 312-2208		
Signature	<i>Tod A. Myrum</i>		Date
			08-25-06
<b>Certificate of Mailing</b>			
I certify that this correspondence and the identified documents listed on this transmittal are being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Mail Stop: ISSUE FEE, Commissioner for Patents, P. O. Box 1450, Alexandria, VA 22313-1450 on August 24, 2006.			
Name	Susan W. Donovan	Signature	<i>Susan W. Donovan</i>

(LARGE ENTITY TRANSMITTAL UNDER 37 CFR § 1.8)



First Named Inventor	Zhongze Wang	COMMENTS ON EXAMINER'S STATEMENT OF REASONS FOR ALLOWANCE
Serial No.	10/758,059	
Filing Date	January 15, 2004	
Group Art Unit	2823	
Examiner Name	Thanh V. Pham	
Allowed	June 26, 2006	
Confirmation No.	5110	
Attorney Docket No.	400.147US02	
Title: FET HAVING EPITAXIAL SILICON GROWTH		

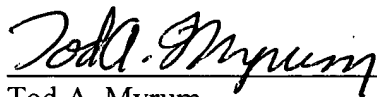
Mail Stop: ISSUE FEE  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Applicant notes that the allowed claims define over the prior art for many different reasons. The stated reasons in the Reasons for Allowance should be interpreted as highlighting only one of the many differences between prior art and the claimed invention. Further, certain claimed limitations not discussed in the statement, particularly in dependent claims, provide additional reasons for patentability.

If the Examiner has any questions or concerns regarding this application, please contact the undersigned at (612) 312-2208.

Respectfully submitted,

Date: 08-25-06

  
\_\_\_\_\_  
Tod A. Myrum  
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